SKNH 56



SEMIPACK® 1

Modules with Thyristor and Free-Wheeling Diode

SKNH 56

Features

- Heat transfer through ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532
- Electrical data see also data sheet SKKH 57

Typical Applications

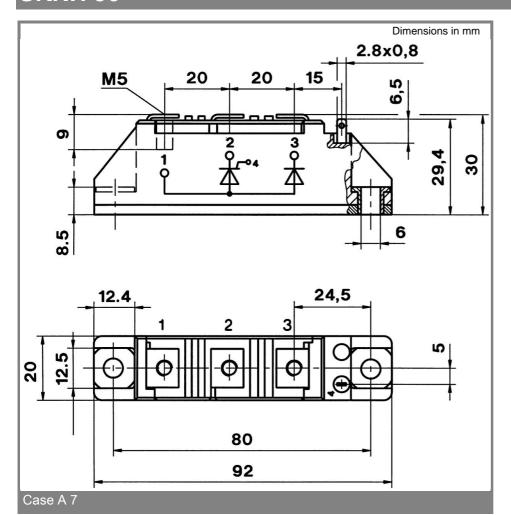
 Special modules for DC braking of AC induction motors

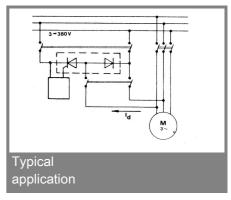
V_{RSM}	V_{RRM}, V_{DRM}	I _{TRMS} = 95 A (maximum value for continuous operation)	
V	V	I _{TAV} = 50 A (sin. 180; T _c = 85 °C)	
1300	1200	SKNH 56/12E	
1500	1400	SKNH 56/14E	
1700	1600	SKNH 56/16E	
1900	1800	SKNH 56/18E	

Symbol	Conditions	Values	Units
I _{TAV}	sin. 180; T _c = 85 (100) °C	50 (35)	Α
I_D	P3/120; T _a = 45 °C;	70	Α
I _{TSM}	T _{vi} = 25 °C; 10 ms	1500	Α
	T_{vi}^{3} = 125 °C; 10 ms	1250	Α
i²t	T _{vj} = 25 °C; 8,3 10 ms	11000	A²s
	T _{vj} = 125 °C; 8,3 10 ms	8000	A²s
V _T	T _{vj} = 25 °C; I _T = 200 A	max. 1,65	V
$V_{T(TO)}$	T _{vi} = 125 °C	max. 0,9	V
r _T	T _{vj} = 125 °C	max. 3,5	mΩ
$I_{DD}; I_{RD}$	$T_{vj} = 25 \text{ °C}; V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 15	mA
t _{gd}	$T_{vj} = 25 \text{ °C}; I_G = 1 \text{ A}; di_G/dt = 1 \text{ A/}\mu\text{s}$	1	μs
t _{gr}	$V_{\rm D} = 0.67 * V_{\rm DRM}$	2	μs
(di/dt) _{cr}	T _{vi} = 125 °C	max. 100	A/µs
(dv/dt) _{cr}	T _{vi} = 125 °C	max. 1000	V/µs
t _q	T _{vi} = 125 °C	50 150	μs
I _H	$T_{vj}^{3} = 25 ^{\circ}\text{C}; \text{ typ. / max.}$	/ 250	mA
IL	T_{vj} = 25 °C; R_G = 33 Ω; typ. / max.	/ 600	mA
V _{GT}	T _{vi} = 25 °C; d.c.	min. 3	V
I_{GT}	$T_{vi} = 25 ^{\circ}\text{C}; \text{d.c.}$	min. 150	mA
V_{GD}	$T_{vj} = 125 ^{\circ}\text{C}; \text{d.c.}$	max. 0,25	V
I_{GD}	$T_{vj} = 125 ^{\circ}\text{C}; \text{d.c.}$	max. 6	mA
R _{th(j-c)}	cont.; per thyristor / per diode	0,57	K/W
R _{th(j-c)}	sin. 180; per thyristor / per diode	0,6	K/W
R _{th(j-c)}	sin. 180; per module	0,3	K/W
R _{th(c-s)}	per thyristor / per module	0,2 / 0,1	K/W
T_{v_i}		- 40 + 125	°C
T _{stg}		- 40 + 125	°C
V _{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
M_s	to heatsink	5 ± 15 %	Nm
M _t	to terminals	5 ± 15 %	Nm
a		5 * 9,81	m/s²
m	approx.	120	g
Case		A 7	



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